

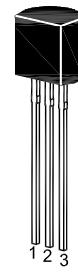
2SC2786

NPN Silicon Epitaxial Planar Transistor

for FM RF amplifier and local oscillator of FM tuner.

The transistor is subdivided into three groups M, L, and K, according to its DC current gain.

On special request, these transistors can be manufactured in different pin configurations.



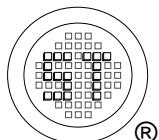
1. Emitter 2. Collector 3. Base
TO-92 Plastic Package

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	30	V
Collector Emitter Voltage	V_{CEO}	20	V
Emitter Base Voltage	V_{EBO}	4	V
Collector Current	I_C	20	mA
Base Current	I_B	20	mA
Power Dissipation	P_{tot}	250	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_{CE} = 6 \text{ V}$, $I_C = 1 \text{ mA}$	h_{FE}	40	-	80	-
	h_{FE}	60	-	120	-
	h_{FE}	90	-	180	-
Collector Base Cutoff Current at $V_{CB} = 30 \text{ V}$	I_{CBO}	-	-	100	nA
Emitter Base Cutoff Current at $V_{EB} = 4 \text{ V}$	I_{EBO}	-	-	100	nA
Collector Emitter Saturation Voltage at $I_C = 10 \text{ mA}$, $I_B = 1 \text{ mA}$	$V_{CE(sat)}$	-	-	0.3	V
Gain Bandwidth Product at $V_{CE} = 6 \text{ V}$, $I_E = -1 \text{ mA}$	f_T	-	600	-	MHz
Output Capacitance at $V_{CB} = 6 \text{ V}$, $f = 1 \text{ MHz}$	C_{ob}	-	-	1.3	pF



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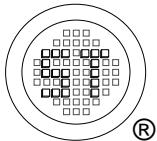
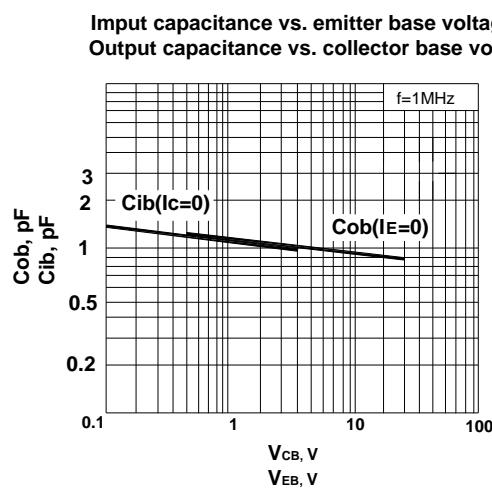
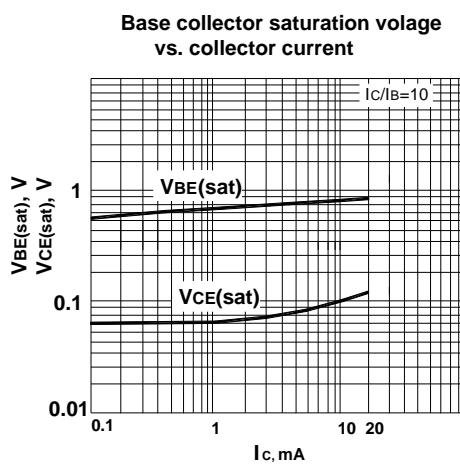
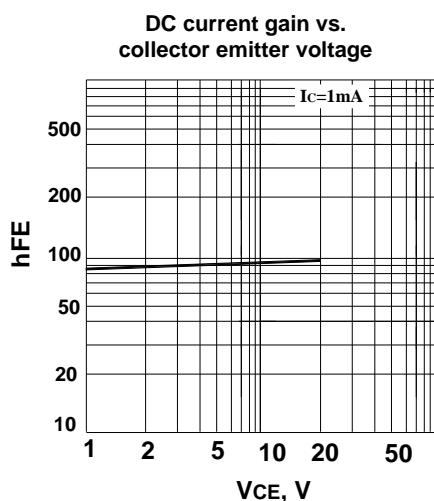
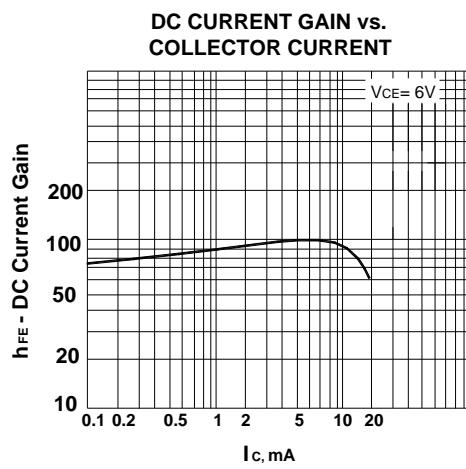
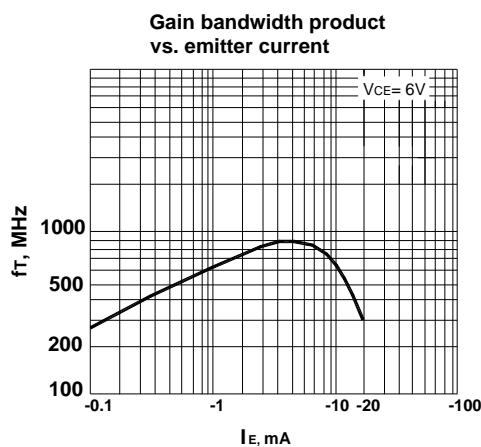
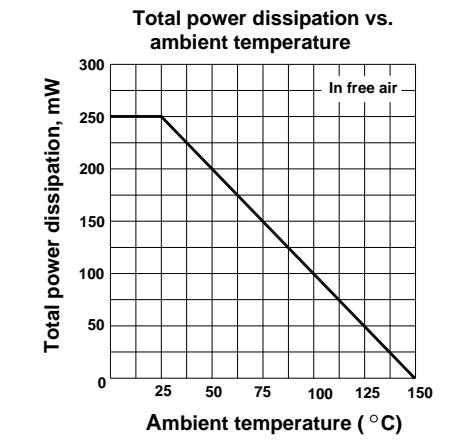
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